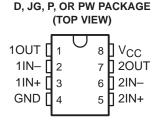
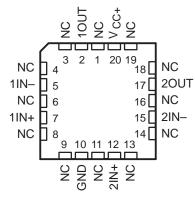
- Wide Range of Supply Voltages:
 - Single Supply . . . 3 V to 30 V (LM2904 and LM2904Q . . . 3 V to 26 V) or
 - Dual Supplies
- Low Supply-Current Drain Independent of Supply Voltage . . . 0.7 mA Typ
- **Common-Mode Input Voltage Range** Includes Ground, Allowing Direct Sensing **Near Ground**
- **Low Input Bias and Offset Parameters:**
 - Input Offset Voltage . . . 3 mV Typ A Versions . . . 2 mV Typ
 - Input Offset Current . . . 2 nA Typ
 - Input Bias Current . . . 20 nA Typ A Versions . . . 15 nA Typ
- **Differential Input Voltage Range Equal to** Maximum-Rated Supply Voltage . . . ±32 V (LM2904 and LM2904Q . . . ±26 V)
- **Open-Loop Differential Voltage** Amplification . . . 100 V/mV Typ
- **Internal Frequency Compensation**



LM158, LM158A . . . FK PACKAGE (TOP VIEW)



NC - No internal connection

description

These devices consist of two independent, high-gain, frequency-compensated operational amplifiers designed to operate from a single supply over a wide range of voltages. Operation from split supplies also is possible if the difference between the two supplies is 3 V to 30 V (3 V to 26 V for the LM2904 and LM2904Q), and $V_{\rm CC}$ is at least 1.5 V more positive than the input common-mode voltage. The low supply-current drain is independent of the magnitude of the supply voltage.

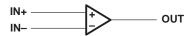
Applications include transducer amplifiers, dc amplification blocks, and all the conventional operational amplifier circuits that now can be more easily implemented in single-supply-voltage systems. For example, these devices can be operated directly from the standard 5-V supply used in digital systems and easily provides the required interface electronics without additional ±5-V supplies.

The LM2904Q is manufactured to demanding automotive requirements.

The LM158 and LM158A are characterized for operation over the full military temperature range of -55°C to 125°C. The LM258 and LM258A are characterized for operation from -25°C to 85°C, the LM358 and LM358A from 0°C to 70°C, and the LM2904 and LM2904Q from -40°C to 125°C.

logic diagram (each amplifier)

PRODUCTION DATA information is current as of publication date. Products conform to specifications per the terms of Texas Instruments standard warranty. Production processing does not necessarily include testing of all parameters.





Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



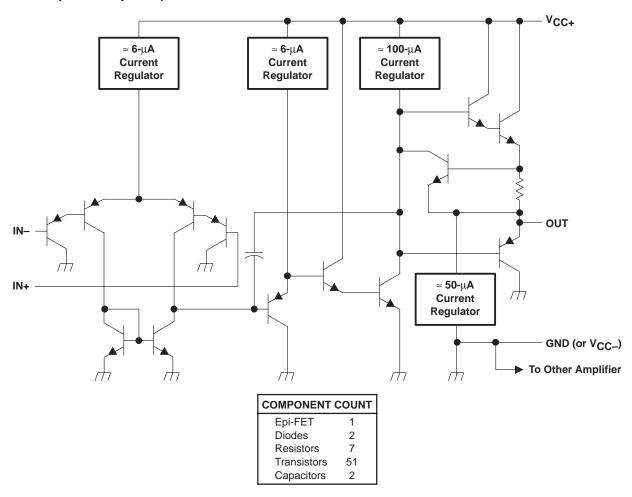
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AVAILABLE OPTIONS

		PACKAGED DEVICES							
TA	V _{IO(max}) AT 25°C	SMALL OUTLINE (D) [†]	CHIP CARRIER (FK)	CERAMIC DIP (JG)	PLASTIC DIP (P)	TSSOP (PW)‡	CHIP FORM (Y)		
0°C to 70°C	7 mV	LM358D	_	_	LM358P	LM358PW	LM358Y		
0.0 10 70.0	3 mV	_	_	_	LM358AP	_	_		
–25°C to 85°C	5 mV	LM258D	_	_	LM258P	_	_		
-25 C to 65 C	3 mV	_	_	_	LM258AP	_	_		
-40°C to 125°C	7 mV	LM2904D	_	_	LM2904P	LM2904PW	_		
-40 C to 125 C	7 IIIV	LM2904QD	_	_	LM2904QP	_	_		
–55°C to 125°C	5 mV	LM158D	LM158FK	LM158JG	LM158P	_			
-55 C to 125°C	2 mV	_	LM158AFK	LM158AJG	_	_	_		

[†] The D package is available taped and reeled. Add the suffix R to the device type (e.g., LM358DR).

schematic (each amplifier)

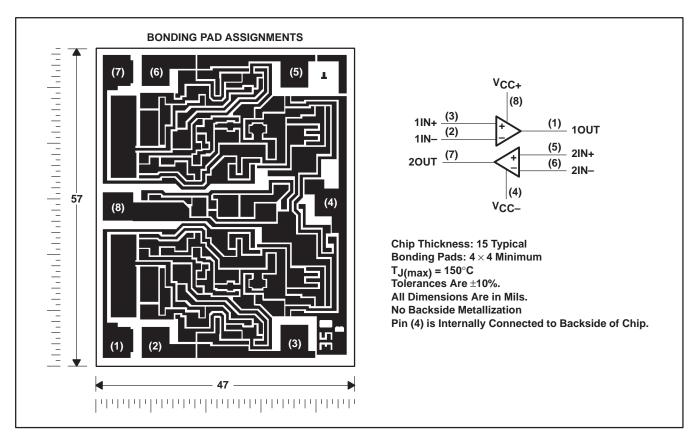




[‡]The PW package is only available left-end taped and reeled.

LM358Y chip information

These chips, when properly assembled, display characteristics similar to the LM358. Thermal compression or ultrasonic bonding can be used on the doped-aluminum bonding pads. Chips can be mounted with conductive epoxy or a gold-silicon preform.



LM158, LM158A, LM258, LM258A LM358, LM358A, LM358Y, LM2904, LM2904Q **DUAL OPERATIONAL AMPLIFIERS**

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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

		LM158, LM158A LM258, LM258A LM358, LM358A	LM2904 LM2904Q	UNIT	
Supply voltage, V _{CC} (see Note 1)		32	26	V	
Differential input voltage, V _{ID} (see Note 2)		±32	±26	V	
Input voltage, V _I (either input)	-0.3 to 32				
Duration of output short circuit (one amplifier) to ground at (or below) 25°C free-air temperature (V _{CC} ≤ 15 V) (see Note 3)	Unlimited	Unlimited			
Continuous total power dissipation	otal power dissipation See Dissipation F			ble	
	LM158, LM158A	-55 to 125			
Operation from air temperature range. T.	LM258, LM258A	-25 to 85		°C	
Operating free-air temperature range, TA	LM358, LM358A	0 to 70			
	LM2904, LM2904Q		26 ±26 -0.3 to 26 Unlimited		
Storage temperature range, T _{Stg}		-65 to 150	-65 to 150	°C	
Case temperature for 60 seconds	FK package	260		°C	
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds	JG package	300	300	°C	
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	D, P, or PW package	260	260	°C	

- NOTES: 1. All voltage values, except differential voltages and VCC specified for measurement of IOS, are with respect to the network ground
 - 2. Differential voltages are at IN+ with respect to IN-.
 - 3. Short circuits from outputs to $V_{\hbox{\scriptsize CC}}$ can cause excessive heating and eventual destruction.

DISSIPATION RATING TABLE

		2.0070			
PACKAGE	$T_A \le 25^{\circ}C$ POWER RATING	DERATING FACTOR ABOVE T _A = 25°C	T _A = 70°C POWER RATING	T _A = 85°C POWER RATING	T _A = 125°C POWER RATING
D	725 mW	5.8 mW/°C	464 mW	377 mW	145 mW
FK	1375 mW	11.0 mW/°C	880 mW	715 mW	275 mW
JG	1050 mW	8.4 mW/°C	672 mW	546 mW	210 mW
Р	1000 mW	8.0 mW/°C	640 mW	520 mW	200 mW
PW	525 mW	4.2 mW/°C	336 mW	273 mW	_



PARAMETER		TEST CONDITIONS†		TA‡		LM158 LM258		LM358			UNIT
					MIN	TYP§	MAX	MIN	TYP§	MAX	
		$V_{CC} = 5 V to$		25°C		3	5		3	7	
VIO	Input offset voltage	$V_{IC} = V_{ICR}(n)$ $V_{O} = 1.4 \text{ V}$	nin),	Full range			7			9	mV
αΝΙΟ	Average temperature coefficient of input offset voltage			Full range		7			7		μV/°C
IIO	Input offset current	V _O = 1.4 V		25°C Full range		2	30 100		2	50 150	nA
αΙΙΟ	Average temperature coefficient of input offset current			Full range		10	100		10	130	pA/°C
lin	Input bias current	V _O = 1.4 V		25°C		-20	-150		-20	-250	nA
IB	input bias current	VO = 1.4 V		Full range			-300			-500	ПА
Vion	Common-mode	\/a a = 5 \/ ta	MAA V	25°C	0 to V _{CC} -1.5	i		0 to V _{CC} -1.5			
VICR input voltage range	V _{CC} = 5 V to MAX		Full range	0 to V _{CC} -2			0 to V _{CC} -2			V	
		$R_L \ge 2 k\Omega$		25°C	V _{CC} -1.5	;		V _{CC} -1.5			
V	High-level output voltage	$R_L \ge 10 \text{ k}\Omega$		25°C							V
VOH		V _{CC} = MAX	$R_L = 2 k\Omega$	Full range	26			26			V
		ACC = INIAX	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28		27	28		
V_{OL}	Low-level output voltage	R _L ≤ 10 kΩ		Full range		5	20		5	20	mV
	Large-signal	$V_{CC} = 15 \text{ V},$		25°C	50	100		25	100		
AVD	differential voltage amplification	$V_0 = 1 \text{ V to } 1$ $R_L = \ge 2 \text{ k}\Omega$	1 V,	Full range	25			15			V/mV
CMRR	Common-mode rejection ratio	$V_{CC} = 5 \text{ V to}$ $V_{IC} = V_{ICR}(n)$		25°C	70	80		65	80		dB
k _{SVR}	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{CC} = 5 V to	,	25°C	65	100		65	100		dB
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1 kHz to 2	0 kHz	25°C		120			120		dB
		V _{CC} = 15 V, V	V _{ID} = 1 V,	25°C	-20	-30		-20	-30		
		$V_O = 0$		Full range	-10			-10			mA
IO	Output current	V _{CC} = 15 V, V	$V_{ID} = -1 V$	25°C	10	20		10	20		111/4
		V _O = 15 V		Full range	5			5			
		$V_{ID} = -1 V$,	V _O = 200 mV	25°C	12	30		12	30		μΑ
los	Short-circuit output current	V_{CC} at 5 V, Q_{CC}	GND at -5 V,	25°C		±40	±60		±40	±60	mA
	Supply current	$V_0 = 2.5 V$,	No load	Full range		0.7	1.2		0.7	1.2	
ICC	(two amplifiers)	V _{CC} = MAX, No load	V _O = 0.5 V,	Full range		1	2		1	2	mA

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for LM 2904 and 30 V for others.

[‡] Full range is -55° C to 125° C for LM158, -25° C to 85° C for LM258, 0° C to 70° C for LM358, and -40° C to 125° C for LM2904 and LM2904Q. § All typical values are at $T_{A} = 25^{\circ}$ C.



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PARAMETER		TEST CONDITIONS [†]		T _A ‡		.M2904 M2904Q		UNIT
						MAX		
VIO	Input offset voltage	$V_{CC} = 5 \text{ V to MAX},$		25°C		3	7	mV
VIO	input onset voitage	$V_{IC} = V_{ICR(min)}$	$V_0 = 1.4 \text{ V}$	Full range			10	IIIV
ανιο	Average temperature coefficient of input offset voltage			Full range		7		μV/°C
	hand effect coment	V 44V		25°C		2	50	A
110	Input offset current	V _O = 1.4 V		Full range			300	nA
αΙΙΟ	Average temperature coefficient of input offset current			Full range		10		pA/°C
	Langet bing assessed	V 44V		25°C		-20	-250	A
ΙΒ	Input bias current	V _O = 1.4 V		Full range			-500	nA
.,		.,,		25°C	0 to V _{CC} -1.5			.,
VICR	Common-mode input voltage range	V _{CC} = 5 V to MAX		Full range	0 to V _{CC} -2			V
		$R_L \ge 2 k\Omega$		25°C				
.,	High-level output voltage	$R_L \ge 10 \text{ k}\Omega$		25°C	V _{CC} -1.5			V
VOH		V MAY	$R_L = 2 k\Omega$	Full range	26			V
		VCC = MAX	R _L ≥ 10 kΩ	Full range	23	24		
VOL	Low-level output voltage	R _L ≤ 10 kΩ		Full range		5	20	mV
Λ	Large-signal differential	V _{CC} = 15 V, V _O =	= 1 V to 11 V,	25°C	25	100		V/mV
AVD	voltage amplification	$R_L = \ge 2 k\Omega$		Full range	15			V/IIIV
CMRR	Common-mode rejection ratio	$V_{CC} = 5 \text{ V to MAX}$ $V_{IC} = V_{ICR(min)}$, ,	25°C	50	80		dB
ksvr	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})	V _{CC} = 5 V to MAX	(25°C	65	100		dB
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1 kHz to 20 kHz	Z	25°C		120		dB
		V 45 V V-	4) /) / - 0	25°C	-20	-30		
		V _{CC} = 15 V, V _{ID} =	: 1 V, VO = 0	Full range	-10			A
IO	Output current	V 45 V V	4 \ / \ / - 4 = \ /	25°C	10	20		mA
		V _{CC} = 15 V, V _{ID} =	:-1 v, vO = 15 v	Full range	5			
		$V_{ID} = -1 V$,	V _O = 200 mV	25°C		30		μΑ
los	Short-circuit output current	V _{CC} at 5 V, GND a	$at - 5 \text{ V, V}_0 = 0$	25°C		±40	±60	mA
laa	Cumply ourrent (two amplifican)	V _O = 2.5 V,	No load	Full range		0.7	1.2	mΛ
Icc	Supply current (two amplifiers)	V _{CC} = MAX, V _O =	0.5 V, No load	Full range		1	2	mA

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 26 V for LM 2904 and 30 V for others.



[‡] Full range is -55° C to 125° C for LM158, -25° C to 85° C for LM258, 0° C to 70° C for LM358, and -40° C to 125° C for LM2904 and LM2904Q. § All typical values are at $T_{A} = 25^{\circ}$ C.

PARAMETER		TEST CONDITIONS†		- +	L	M158A		LM258A			UNIT
				T _A ‡	MIN	TYP§	MAX	MIN	TYP§	MAX	UNII
.,		$V_{CC} = 5 V to$		25°C			2		2	3	.,
VIO	Input offset voltage	V _{IC} = V _{ICR} (n V _O = 1.4 V	nin) [,]	Full range			4			4	mV
αVIO	Average temperature coefficient of input offset voltage			Full range		7	15*		7	15	μV/°C
lio	Input offset current	V _O = 1.4 V		25°C		2	10		2	15	nA
lio	input onset current	VO = 1.4 V		Full range			30			30	IIA
αIIO	Average temperature coefficient of input offset current			Full range		10	200		10	200	pA/°C
l	V _O = 1.4 V		25°C		-15	-50		-15	-80	nA	
liΒ	Input bias current	VO = 1.4 V		Full range			-100			-100	11/4
V. 0.5	Common-mode input voltage range	V _{CC} = 30 V		25°C	0 to V _{CC} -1.5	;		0 to V _{CC} -1.5	5		٧
VICR				Full range	0 to V _{CC} -2			0 to V _{CC} -2			
	LPak Laval	$R_L \ge 2 k\Omega$		25°C	V _{CC} -1.5	;		V _{CC} -1.5	5		
Vон	High-level output voltage	V _{CC} = 30 V	$R_L = 2 k\Omega$	Full range	26			26			\ \
		VCC = 30 V	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28		27	28		
VOL	Low-level output voltage	R _L ≤ 10 kΩ		Full range		5	20		5	20	mV
Δ	Large-signal	V _{CC} = 15 V,	4.17	25°C	50	100		50	100		\//\/
AVD	differential voltage amplification	$V_O = 1 \text{ V to } 1$ $R_L = \ge 2 \text{ k}\Omega$	1 V,	Full range	25			25			V/mV
CMRR	Common-mode rejection ratio			25°C	70	80		70	80	_	dB
kSVR	Supply-voltage rejection ratio (ΔV _{DD} /ΔV _{IO})			25°C	65	100		65	100		dB
V _{O1} /V _{O2}	Crosstalk attenuation	f = 1 kHz to 2	0 kHz	25°C		120			120		dB

^{*}On products compliant to MIL-PRF-38535, this parameter is not production tested.

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified.

 $[\]ddagger$ Full range is -55° C to 125° C for LM158A, -25° C to 85° C for LM258A, and 0° C to 70° C for LM358A.

[§] All typical values are at $T_A = 25$ °C.

LM158, LM158A, LM258, LM258A LM358, LM358A, LM358Y, LM2904, LM2904Q DUAL OPERATIONAL AMPLIFIERS

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PARAMETER		TEST CONDITIONS!		TA‡	LM358A			UNIT
	PARAMETER		TEST CONDITIONS†			TYP§	MAX	UNII
V	Input offeet voltage	V _{CC} = 5 V to 30 V	V _{CC} = 5 V to 30 V,			2	3	mV
VIO	Input offset voltage	VIC = VICR(min),	V _O = 1.4 V	Full range			5	IIIV
ανιο	Average temperature coefficient of input offset voltage			Full range		7	20	μV/°C
lio	Input offset current	V _O = 1.4 V		25°C		2	30	nA
lio	input onset current	VO = 1.4 V		Full range			75	IIA
αΙΙΟ	Average temperature coefficient of input offset current			Full range		10	300	pA/°C
L. Landbird comment		V 44V		25°C		-15	-100	nA
IB	Input bias current	V _O = 1.4 V		Full range			-200	nA
V ₁ = -	Common-mode input voltage range	V _{CC} = 30 V		25°C	0 to V _{CC} -1.5			٧
VICR	Common-mode input voltage range			Full range	0 to V _{CC} -2			V
		$R_L \ge 2 k\Omega$		25°C	V _{CC} -1.5			
Vон	High-level output voltage	V 20 V	$R_L = 2 k\Omega$	Full range	26			V
		ACC = 30 A	$R_L \ge 10 \text{ k}\Omega$	Full range	27	28		
VOL	Low-level output voltage	R _L ≤ 10 kΩ		Full range		5	20	mV
Δ	Large-signal differential	V _{CC} = 15 V, V _O =	1 V to 11 V,	25°C	25	100		V/mV
AVD	voltage amplification	$R_L = \ge 2 k\Omega$		Full range	15			V/IIIV
CMRR	Common-mode rejection ratio			25°C	65	80		dB
k _{SVR}	Supply-voltage rejection ratio $(\Delta V_{DD}/\Delta V_{IO})$			25°C	65	100		dB
VO1/VO2	Crosstalk attenuation	f = 1 kHz to 20 kH:		25°C		120		dB

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified.

[‡] Full range is –55°C to 125°C for LM158A, –25°C to 85°C for LM258A, and 0°C to 70°C for LM358A.

[§] All typical values are at $T_A = 25$ °C.

electrical characteristics V_{CC} = 5 V, T_A = 25°C (unless otherwise noted)

DADAMETED			LN	/I358Y		UNIT		
	PARAMETER	l le:	TEST CONDITIONS†					ONIT
VIO	Input offset voltage					3	7	mV
lio	Input offset current	$V_{CC} = 5 V \text{ to MAX},$	$V_{IC} = V_{ICR(min)}$	$V_0 = 1.4 \ V$		2	50	nA
I _{IB}	Input bias current					-20	-250	nA
VICR	Common-mode input voltage range	V _{CC} = 5 V to MAX			0 to V _{CC} -1.5			V
V _{OH+}	High-level output voltage	$R_L \ge 10 \text{ k}\Omega$			V _{CC} -1.5			V
A _{VD}	Large-signal differential voltage amplification	V _{CC} = 15 V,	V _O = 1 V to 11 V,	$R_L = \ge 2 k\Omega$	15	100		V/mV
CMRR	Common-mode rejection ratio	V _{IC} = V _{ICR(min)}			65	80		dB
ksvr	Supply-voltage rejection ratio $(\Delta V_{CC\pm}/\Delta V_{IO})$				65	100		dB
		V-0 45 V	V _{ID} = 1 V,	VO = 0	-20	-30	-60	
IO	Output current	V _{CC} = 15 V	$V_{ID} = -1 V$,	V _O = 15 V	10	20		mA
		V _{ID} = 1 V,	V _O = 200 mV		12	30		
los	Short-circuit output current	V _{CC} at 5 V,	GND at -5 V,	V _O = 0		±40	±60	mA
loo	Supply current (four amplifiers)	$V_0 = 2.5 V$,	No load			0.7	1.2	mA
lcc	Supply current (four amplifiers)	V _{CC} = MAX,	$V_0 = 0.5 V$,	No load		1	2	IIIA

[†] All characteristics are measured under open-loop conditions with zero common-mode input voltage, unless otherwise specified. MAX V_{CC} for testing purposes is 30 V.

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